



Construction of the heterostructure of NiPt truncated octahedral nanoparticle/MoS₂ and its interfacial structure evolution

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1. EDS spectrum of NiPt TONPs

The NiPt TONPs prepared by the solvothermal method were loaded onto MoS₂ nanosheets by the ultrasonic assembly. Then the product was ultrasonically dispersed in ethanol and dropped by a pipette on a Cu TEM grid coated with porous carbon film. Figure S1 shows the composition investigated by EDS. Except for the characteristic peaks of Cu elements in the Cu TEM grid, only the peaks of Ni and Pt elements were observed. It is reasonable to conclude that the synthesized products only consist of Ni and Pt elements.

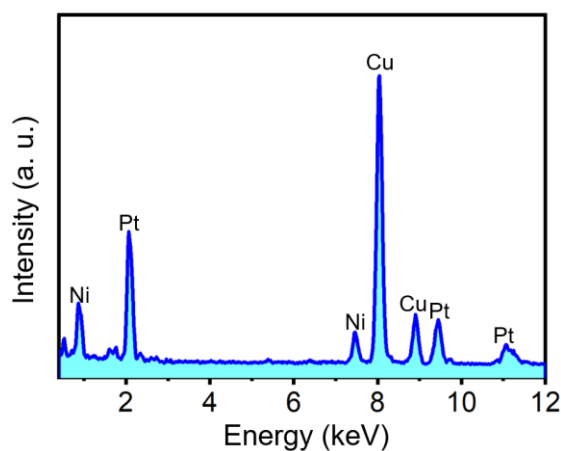


Figure S1. EDS spectrum of NiPt TONPs.

2. Structure evolution of a NiPt TONP on MoS₂ under electron beam irradiation

Figure S2 shows the dynamic structure evolution of a NiPt TONP on MoS₂ under electron beam irradiation. With time elapse, the NP on MoS₂ was quite stable and the crystallinity was promoted. By measuring the d-spacings and the corresponding angles in Fig. S2a₂, it can be calibrated as the crystal zone axis [331] of 2H-MoS₂ and (111) crystal plane of NiPt. As indicated by the white dashed frames in Figs. S2a₂–S2d₂, the NP and MoS₂ have a crystallographic orientation relationship of (111)_{NiPt}//($\bar{1}03$)_{MoS₂}. The result indicates that the NiPt TONP with lattice match to MoS₂ was very stable during the ultrasonic assembly process.



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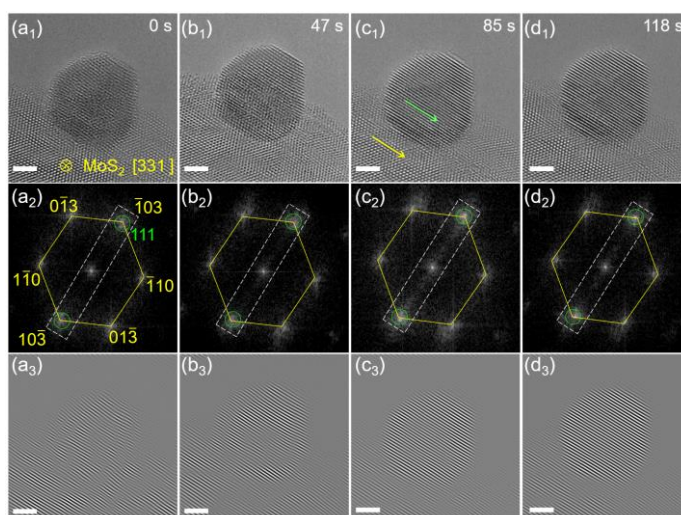


Figure S2. (a₁–d₁) Time series HRTEM images of a NiPt TONP on MoS₂ at 0, 47, 85, and 118 s; (a₂–d₂) FFT patterns corresponding to (a₁–d₁); (a₃–d₃) Inverse FFT patterns corresponding to the green circles in (a₂–d₂). The scale bars are all 2 nm.

3. Structure evolution of another NiPt TONP on MoS₂ under electron beam irradiation

Figure S3 shows the dynamic structure evolution of a NiPt TONP on MoS₂ under electron beam irradiation. With time elapse, the shape of the NP was changed, probably due to the diffusion of surface atoms on the exposed crystal facets. According to the d-spacings and the corresponding angle in Fig. S3b₂, it can be calibrated as the crystal zone axis [221] of 2H-MoS₂ and [031] of NiPt. From Figs. S3a₂–S3d₂, it can be seen that the NP rotated under electron beam irradiation to achieve a lattice matching relationship with MoS₂ of $(1\bar{1}3)_{\text{NiPt}} // (0\bar{2}4)_{\text{MoS}_2}$, $[031]_{\text{NiPt}} // [221]_{\text{MoS}_2}$.

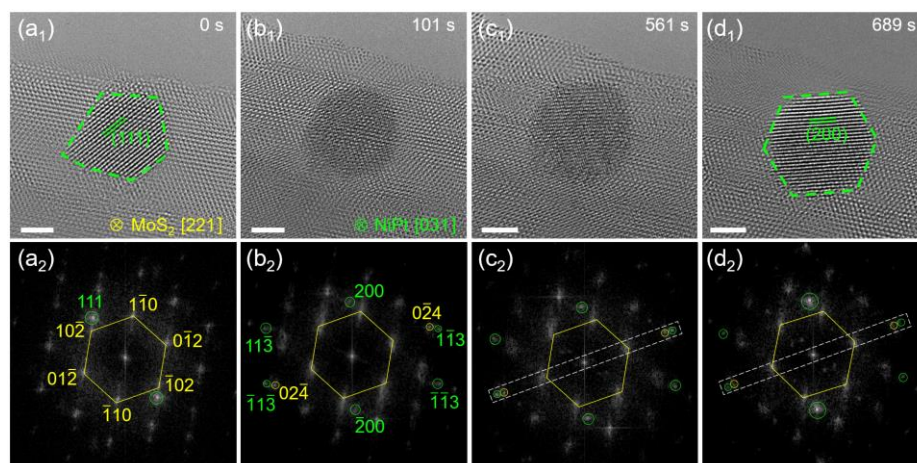


Figure S3. (a₁–d₁) Time series HRTEM images of a NiPt TONP on MoS₂ at 0, 101, 561, and 689 s; (a₂–d₂) FFT patterns corresponding to (a₁–d₁). The scale bars are all 2 nm.

4. Coalescence of two adjacent NiPt TONPs on MoS₂ under electron beam irradiation

Figure S4 shows the coalescence behavior of two adjacent NiPt TONPs on MoS₂ irradiated by the electron beam. With time elapse, the NP “2” undergoes a rotation and achieves the same lattice orientation at the interface of the two NPs.

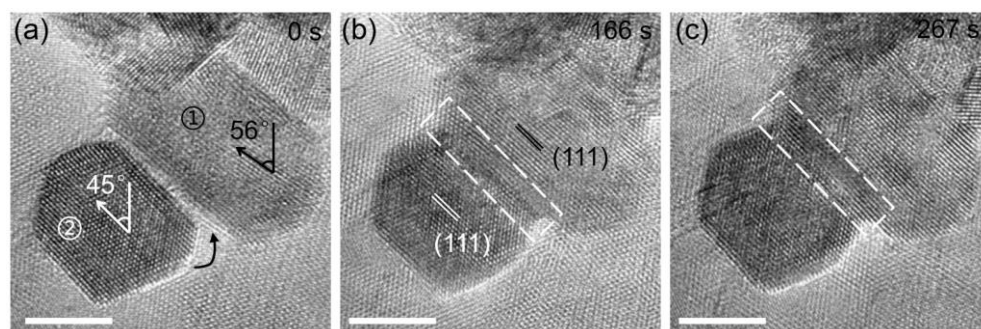


Figure S4. (a–c) Time-series TEM images of the coalescence of two adjacent NiPt TONPs on MoS₂ at 0, 166, and 267 s. The scale bars are all 5 nm.

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